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#### Details

Product Status	Active
Core Processor	PIC
Core Size	8-Bit
Speed	4MHz
Connectivity	-
Peripherals	POR, WDT
Number of I/O	20
Program Memory Size	768B (512 x 12)
Program Memory Type	OTP
EEPROM Size	-
RAM Size	25 x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	-
Oscillator Type	External
Operating Temperature	0°C ~ 70°C (TA)
Mounting Type	Surface Mount
Package / Case	28-SSOP (0.209", 5.30mm Width)
Supplier Device Package	28-SSOP
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic16c55a-04-ss

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### **Table of Contents**

4.0		-
1.0	General Description	5
2.0	PIC16C5X Device Varieties	7
3.0	Architectural Overview	9
4.0	Oscillator Configurations	. 15
5.0	Reset	. 19
6.0	Memory Organization	. 25
7.0	I/O Ports	. 35
8.0	Timer0 Module and TMR0 Register	. 37
9.0	Special Features of the CPU	. 43
10.0	Instruction Set Summary	. 49
11.0	Development Support	. 61
12.0	Electrical Characteristics - PIC16C54/55/56/57	. 67
13.0	Electrical Characteristics - PIC16CR54A	. 79
14.0	Device Characterization - PIC16C54/55/56/57/CR54A	. 91
15.0	Electrical Characteristics - PIC16C54A	103
16.0	Device Characterization - PIC16C54A	117
17.0	Electrical Characteristics - PIC16C54C/CR54C/C55A/C56A/CR56A/C57C/CR57C/C58B/CR58B	131
18.0	Device Characterization - PIC16C54C/CR54C/C55A/C56A/CR56A/CR56A/CR57C/CR57C/C58B/CR58B	145
19.0	Electrical Characteristics - PIC16C54C/C55A/C56A/C57C/C58B 40MHz	155
20.0	Device Characterization - PIC16C54C/C55A/C56A/C57C/C58B 40MHz	165
21.0	Packaging Information	171
Appe	ndix A: Compatibility	182
On-L	ne Support	187
Read	er Response	188
Produ	uct Identification System	189

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### TABLE 1-1: PIC16C5X FAMILY OF DEVICES

Features	PIC16C54	PIC16CR54	PIC16C55	PIC16C56	PIC16CR56			
Maximum Operation Frequency	40 MHz	20 MHz	40 MHz	40 MHz	20 MHz			
EPROM Program Memory (x12 words)	512	—	512	1K	—			
ROM Program Memory (x12 words)	—	512	—	—	1K			
RAM Data Memory (bytes)	25	25	24	25	25			
Timer Module(s)	TMR0	TMR0	TMR0	TMR0	TMR0			
I/O Pins	12	12	20	12	12			
Number of Instructions	33	33	33	33	33			
Packages	18-pin DIP, SOIC; 20-pin SSOP	18-pin DIP, SOIC; 20-pin SSOP	28-pin DIP, SOIC; 28-pin SSOP	18-pin DIP, SOIC; 20-pin SSOP	18-pin DIP, SOIC; 20-pin SSOP			
All PIC <sup>®</sup> Family devices have Power-on Reset, selectable Watchdog Timer, selectable Code Protect and high I/O current capability.								

PIC16C58 Features **PIC16C57** PIC16CR57 PIC16CR58 Maximum Operation Frequency 20 MHz 40 MHz 40 MHz 20 MHz EPROM Program Memory (x12 words) 2K 2K \_\_\_\_ \_ ROM Program Memory (x12 words) 2K 2K \_ \_ RAM Data Memory (bytes) 72 72 73 73 Timer Module(s) TMR0 TMR0 TMR0 TMR0 I/O Pins 20 20 12 12 Number of Instructions 33 33 33 33 28-pin DIP, SOIC; 28-pin DIP, SOIC; 18-pin DIP, SOIC; 18-pin DIP, SOIC; Packages 28-pin SSOP 28-pin SSOP 20-pin SSOP 20-pin SSOP All PIC® Family devices have Power-on Reset, selectable Watchdog Timer, selectable Code Protect and high I/O current capability.

Din Nome	Pin Number			Pin	Buffer	Deceristics
Pin Name	DIP	SOIC	SSOP	Туре	Туре	Description
RA0	6	6	5	I/O	TTL	Bi-directional I/O port
RA1	7	7	6	I/O	TTL	
RA2	8	8	7	I/O	TTL	
RA3	9	9	8	I/O	TTL	
RB0	10	10	9	I/O	TTL	Bi-directional I/O port
RB1	11	11	10	I/O	TTL	
RB2	12	12	11	I/O	TTL	
RB3	13	13	12	I/O	TTL	
RB4	14	14	13	I/O	TTL	
RB5	15	15	15	I/O	TTL	
RB6	16	16	16	I/O	TTL	
RB7	17	17	17	I/O	TTL	
RC0	18	18	18	I/O	TTL	Bi-directional I/O port
RC1	19	19	19	I/O	TTL	
RC2	20	20	20	I/O	TTL	
RC3	21	21	21	I/O	TTL	
RC4	22	22	22	I/O	TTL	
RC5	23	23	23	I/O	TTL	
RC6	24	24	24	I/O	TTL	
RC7	25	25	25	I/O	TTL	
TOCKI	1	1	2	Ι	ST	Clock input to Timer0. Must be tied to Vss or VDD, if not in use, to reduce current consumption.
MCLR	28	28	28	Ι	ST	Master clear (RESET) input. This pin is an active low RESET to the device.
OSC1/CLKIN	27	27	27	I	ST	Oscillator crystal input/external clock source input.
OSC2/CLKOUT	26	26	26	0	—	Oscillator crystal output. Connects to crystal or resonator in crystal Oscillator mode. In RC mode, OSC2 pin outputs CLKOUT which has 1/4 the frequency of OSC1, and denotes the instruction cycle rate.
Vdd	2	2	3,4	Р	—	Positive supply for logic and I/O pins.
Vss	4	4	1,14	Р		Ground reference for logic and I/O pins.
N/C	3,5	3,5	—	_		Unused, do not connect.

### TABLE 3-2: PINOUT DESCRIPTION - PIC16C55, PIC16C57, PIC16CR57

Legend: I = input, O = output, I/O = input/output, P = power, — = Not Used, TTL = TTL input, ST = Schmitt Trigger input

# PIC16C5X



# FIGURE 5-4: TIME-OUT SEQUENCE ON POWER-UP (MCLR TIED TO VDD): FAST VDD RISE TIME



# FIGURE 5-5: TIME-OUT SEQUENCE ON POWER-UP (MCLR TIED TO VDD): SLOW VDD RISE TIME



### 6.0 MEMORY ORGANIZATION

PIC16C5X memory is organized into program memory and data memory. For devices with more than 512 bytes of program memory, a paging scheme is used. Program memory pages are accessed using one or two STATUS Register bits. For devices with a data memory register file of more than 32 registers, a banking scheme is used. Data memory banks are accessed using the File Selection Register (FSR).

### 6.1 Program Memory Organization

The PIC16C54, PIC16CR54 and PIC16C55 have a 9bit Program Counter (PC) capable of addressing a 512 x 12 program memory space (Figure 6-1). The PIC16C56 and PIC16CR56 have a 10-bit Program Counter (PC) capable of addressing a 1K x 12 program memory space (Figure 6-2). The PIC16CR57, PIC16C58 and PIC16CR58 have an 11-bit Program Counter capable of addressing a 2K x 12 program memory space (Figure 6-3). Accessing a location above the physically implemented address will cause a wraparound.

A NOP at the RESET vector location will cause a restart at location 000h. The RESET vector for the PIC16C54, PIC16CR54 and PIC16C55 is at 1FFh. The RESET vector for the PIC16C56 and PIC16CR56 is at 3FFh. The RESET vector for the PIC16C57, PIC16CR57, PIC16C58, and PIC16CR58 is at 7FFh. See Section 6.5 for additional information using CALL and GOTO instructions.

#### FIGURE 6-1: PIC16C54/CR54/C55 PROGRAM MEMORY MAP AND STACK



### FIGURE 6-2:

### PIC16C56/CR56 PROGRAM MEMORY MAP AND STACK



FIGURE 6-3:

PIC16C57/CR57/C58/ CR58 PROGRAM MEMORY MAP AND STACK



### 6.5.1 PAGING CONSIDERATIONS – PIC16C56/CR56, PIC16C57/CR57 AND PIC16C58/CR58

If the Program Counter is pointing to the last address of a selected memory page, when it increments it will cause the program to continue in the next higher page. However, the page preselect bits in the STATUS Register will not be updated. Therefore, the next GOTO, CALL or modify PCL instruction will send the program to the page specified by the page preselect bits (PA0 or PA<1:0>).

For example, a NOP at location 1FFh (page 0) increments the PC to 200h (page 1). A GOTO xxx at 200h will return the program to address xxh on page 0 (assuming that PA<1:0> are clear).

To prevent this, the page preselect bits must be updated under program control.

### 6.5.2 EFFECTS OF RESET

The Program Counter is set upon a RESET, which means that the PC addresses the last location in the last page (i.e., the RESET vector).

The STATUS Register page preselect bits are cleared upon a RESET, which means that page 0 is pre-selected.

Therefore, upon a RESET, a GOTO instruction at the RESET vector location will automatically cause the program to jump to page 0.

### 6.6 Stack

PIC16C5X devices have a 10-bit or 11-bit wide, two-level hardware push/pop stack.

A CALL instruction will push the current value of stack 1 into stack 2 and then push the current program counter value, incremented by one, into stack level 1. If more than two sequential CALL's are executed, only the most recent two return addresses are stored.

A RETLW instruction will pop the contents of stack level 1 into the program counter and then copy stack level 2 contents into level 1. If more than two sequential RETLW's are executed, the stack will be filled with the address previously stored in level 2. Note that the W Register will be loaded with the literal value specified in the instruction. This is particularly useful for the implementation of data look-up tables within the program memory.

For the RETLW instruction, the PC is loaded with the Top of Stack (TOS) contents. All of the devices covered in this data sheet have a two-level stack. The stack has the same bit width as the device PC, therefore, paging is not an issue when returning from a subroutine.

# 9.0 SPECIAL FEATURES OF THE CPU

What sets a microcontroller apart from other processors are special circuits that deal with the needs of realtime applications. The PIC16C5X family of microcontrollers have a host of such features intended to maximize system reliability, minimize cost through elimination of external components, provide power saving operating modes and offer code protection. These features are:

- Oscillator Selection (Section 4.0)
- RESET (Section 5.0)
- Power-On Reset (Section 5.1)
- Device Reset Timer (Section 5.2)
- Watchdog Timer (WDT) (Section 9.2)
- SLEEP (Section 9.3)
- Code protection (Section 9.4)
- ID locations (Section 9.5)

The PIC16C5X Family has a Watchdog Timer which can be shut off only through configuration bit WDTE. It runs off of its own RC oscillator for added reliability. There is an 18 ms delay provided by the Device Reset Timer (DRT), intended to keep the chip in RESET until the crystal oscillator is stable. With this timer on-chip, most applications need no external RESET circuitry.

The SLEEP mode is designed to offer a very low current Power-down mode. The user can wake up from SLEEP through external RESET or through a Watchdog Timer time-out. Several oscillator options are also made available to allow the part to fit the application. The RC oscillator option saves system cost while the LP crystal option saves power. A set of configuration bits are used to select various options.

# PIC16C5X

IORLW	Inclusive OR literal with W					
Syntax:	[ <i>label</i> ] IORLW k					
Operands:	$0 \le k \le 255$					
Operation:	(W) .OR. (k) $\rightarrow$ (W)					
Status Affected:	Z					
Encoding:	1101 kkkk kkkk					
Description:	The contents of the W register are OR'ed with the eight bit literal 'k'. The result is placed in the W regis- ter.					
Words:	1					
Cycles:	1					
Example:	IORLW 0x35					
Before Instru	ction					
VV =	0x9A					
After Instruct	ion					
VV =	0xBF					
Z =	0					

IORWF	Inclusive OR W with f						
Syntax:	[ label ]	IORWF	f,d				
Operands:	$\begin{array}{l} 0\leq f\leq 31\\ d\in [0,1] \end{array}$						
Operation:	(W).OR.	$(f) \to (de$	st)				
Status Affected:	Z						
Encoding:	0001	00df	ffff				
Description:	register 'f'. If 'd' is 0 the result is placed in the W register. If 'd' is 1 the result is placed back in register 'f'.						
Words:	1						
Cycles:	1						
Example:	IORWF		RESULT, 0				
Before Instru RESULT W After Instruct RESULT W Z	iction = 0: = 0: ion = 0: = 0: = 0	x13 x91 x13 x93					

MOVF	Move f						
Syntax:	[ <i>label</i> ] MOVF f,d						
Operands:	$\begin{array}{l} 0 \leq f \leq 31 \\ d \in [0,1] \end{array}$						
Operation:	$(f) \rightarrow (dest)$						
Status Affected:	Z						
Encoding:	0010 00df ffff						
Description:	The contents of register 'f' is moved to destination 'd'. If 'd' is 0, destination is the W register. If 'd' is 1, the destination is file register 'f'. 'd' is 1 is useful to test a file register since status flag Z is affected.						
Words:	1						
Cycles:	1						
Example:	MOVF FSR, 0						
After Instruc W =	tion - value in FSR register						

MOVLW	Move Lit	teral to W	1				
Syntax:	[ label ]	MOVLW	k				
Operands:	$0 \leq k \leq 255$						
Operation:	$k \rightarrow (W)$						
Status Affected:	None						
Encoding:	1100	kkkk	kkkk				
Description:	The eigh the W re	t bit literal gister.	'k' is load	ed into			
Words:	1						
Cycles:	1						
Example:	MOVLW	0x5A					
After Instruct W =	ion 0x5A						

### 11.13 PICDEM 3 Low Cost PIC16CXXX Demonstration Board

The PICDEM 3 demonstration board is a simple demonstration board that supports the PIC16C923 and PIC16C924 in the PLCC package. It will also support future 44-pin PLCC microcontrollers with an LCD Module. All the necessary hardware and software is included to run the basic demonstration programs. The user can program the sample microcontrollers provided with the PICDEM 3 demonstration board on a PRO MATE II device programmer, or a PICSTART Plus development programmer with an adapter socket, and easily test firmware. The MPLAB ICE in-circuit emulator may also be used with the PICDEM 3 demonstration board to test firmware. A prototype area has been provided to the user for adding hardware and connecting it to the microcontroller socket(s). Some of the features include a RS-232 interface, push button switches, a potentiometer for simulated analog input, a thermistor and separate headers for connection to an external LCD module and a keypad. Also provided on the PICDEM 3 demonstration board is a LCD panel, with 4 commons and 12 segments, that is capable of displaying time, temperature and day of the week. The PICDEM 3 demonstration board provides an additional RS-232 interface and Windows software for showing the demultiplexed LCD signals on a PC. A simple serial interface allows the user to construct a hardware demultiplexer for the LCD signals.

### 11.14 PICDEM 17 Demonstration Board

The PICDEM 17 demonstration board is an evaluation board that demonstrates the capabilities of several Microchip microcontrollers, including PIC17C752, PIC17C756A, PIC17C762 and PIC17C766. All necessary hardware is included to run basic demo programs, which are supplied on a 3.5-inch disk. A programmed sample is included and the user may erase it and program it with the other sample programs using the PRO MATE II device programmer, or the PICSTART Plus development programmer, and easily debug and test the sample code. In addition, the PICDEM 17 demonstration board supports downloading of programs to and executing out of external FLASH memory on board. The PICDEM 17 demonstration board is also usable with the MPLAB ICE in-circuit emulator, or the PICMASTER emulator and all of the sample programs can be run and modified using either emulator. Additionally, a generous prototype area is available for user hardware.

### 11.15 KEELOQ Evaluation and Programming Tools

KEELOQ evaluation and programming tools support Microchip's HCS Secure Data Products. The HCS evaluation kit includes a LCD display to show changing codes, a decoder to decode transmissions and a programming interface to program test transmitters.



### TABLE 12-2: CLKOUT AND I/O TIMING REQUIREMENTS - PIC16C54/55/56/57

AC Char	acteristics	$\begin{array}{ll} \mbox{Standard Operating Conditions (unless operating Temperature} & 0^{\circ}C \leq TA \leq \\ -40^{\circ}C \leq TA \leq \\ -40^{\circ}C \leq TA \leq \end{array}$	s otherwise sp +70°C for comm +85°C for indust +125°C for exter	ecified) ercial rial nded	)	
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units
10	TosH2ckL	OSC1↑ to CLKOUT↓ <sup>(1)</sup>	—	15	30**	ns
11	TosH2ckH	OSC1↑ to CLKOUT↑ <sup>(1)</sup>	—	15	30**	ns
12	TckR	CLKOUT rise time <sup>(1)</sup>	—	5.0	15**	ns
13	TckF	CLKOUT fall time <sup>(1)</sup>	—	5.0	15**	ns
14	TckL2ioV	CLKOUT↓ to Port out valid <sup>(1)</sup>	—	_	40**	ns
15	TioV2ckH	Port in valid before CLKOUT <sup>(1)</sup>	0.25 TCY+30*	_	—	ns
16	TckH2iol	Port in hold after CLKOUT <sup>(1)</sup>	0*	_	—	ns
17	TosH2ioV	OSC1 <sup>↑</sup> (Q1 cycle) to Port out valid <sup>(2)</sup>	—	_	100*	ns
18	TosH2iol	OSC1 <sup>↑</sup> (Q2 cycle) to Port input invalid (I/O in hold time)	TBD	—	—	ns
19	TioV2osH	Port input valid to OSC1↑ (I/O in setup time)	TBD	—	—	ns
20	TioR	Port output rise time <sup>(2)</sup>	—	10	25**	ns
21	TioF	Port output fall time <sup>(2)</sup>	_	10	25**	ns

\* These parameters are characterized but not tested.

\*\* These parameters are design targets and are not tested. No characterization data available at this time.

† Data in the Typical ("Typ") column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

**Note 1:** Measurements are taken in RC Mode where CLKOUT output is 4 x Tosc.

2: Please refer to Figure 12-1 for load conditions.



#### FIGURE 12-4: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER TIMING -PIC16C54/55/56/57

### TABLE 12-3: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER - PIC16C54/55/56/57

AC CharacteristicsStandard Operating Conditions (unless otherwise specified) Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial $-40^{\circ}C \le TA \le +85^{\circ}C$ for industrial $-40^{\circ}C \le TA \le +125^{\circ}C$ for extended							
Param No.	Symbol	Characteristic Min Typ† Max Uni				Units	Conditions
30	TmcL	MCLR Pulse Width (low)	100*	—	_	ns	VDD = 5.0V
31	Twdt	Watchdog Timer Time-out Period (No Prescaler)	9.0*	18*	30*	ms	VDD = 5.0V (Comm)
32	Tdrt	Device Reset Timer Period	9.0*	18*	30*	ms	VDD = 5.0V (Comm)
34	Tioz	I/O Hi-impedance from MCLR Low		_	100*	ns	

\* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

## 13.0 ELECTRICAL CHARACTERISTICS - PIC16CR54A

### Absolute Maximum Ratings(†)

Ambient Temperature under bias	–55°C to +125°C
Storage Temperature	–65°C to +150°C
Voltage on VDD with respect to VSS	0 to +7.5V
Voltage on MCLR with respect to Vss <sup>(1)</sup>	0 to +14V
Voltage on all other pins with respect to Vss	–0.6V to (VDD + 0.6V)
Total power dissipation <sup>(2)</sup>	
Max. current out of Vss pin	150 mA
Max. current into Vod pin	50 mA
Max. current into an input pin (T0CKI only)	±500 μA
Input clamp current, Iık (VI < 0 or VI > VDD)	±20 mA
Output clamp current, IOK (V0 < 0 or V0 > VDD)	±20 mA
Max. output current sunk by any I/O pin	25 mA
Max. output current sourced by any I/O pin	20 mA
Max. output current sourced by a single I/O port (PORTA or B)	40 mA
Max. output current sunk by a single I/O port (PORTA or B)	50 mA

- **Note 1:** Voltage spikes below Vss at the  $\overline{\text{MCLR}}$  pin, inducing currents greater than 80 mA may cause latch-up. Thus, a series resistor of 50 to 100  $\Omega$  should be used when applying a low level to the  $\overline{\text{MCLR}}$  pin rather than pulling this pin directly to Vss.
  - **2:** Power Dissipation is calculated as follows: PDIS = VDD x {IDD  $\sum$  IOH} +  $\sum$  {(VDD-VOH) x IOH} +  $\sum$ (VOL x IOL)

† NOTICE: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.





### 15.1 DC Characteristics: PIC16C54A-04, 10, 20 (Commercial) PIC16C54A-04I, 10I, 20I (Industrial) PIC16LC54A-04 (Commercial) PIC16LC54A-04I (Industrial)

PIC16L0 PIC16L0 (Comm	PIC16LC54A-04 PIC16LC54A-04I (Commercial, Industrial)				$\begin{array}{ll} \mbox{Standard Operating Conditions (unless otherwise specified)} \\ \mbox{Operating Temperature} & 0^{\circ}C \leq TA \leq +70^{\circ}C \mbox{ for commercial} \\ -40^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for industrial} \end{array}$					
PIC16C54A-04, 10, 20 PIC16C54A-04I, 10I, 20I (Commercial, Industrial)			<b>Stand</b> Opera	$\begin{array}{ll} \mbox{Standard Operating Conditions (unless otherwise specified)} \\ \mbox{Operating Temperature} & 0^\circ C \leq T A \leq +70^\circ C \mbox{ for commercial} \\ -40^\circ C \leq T A \leq +85^\circ C \mbox{ for industrial} \end{array}$						
Param No. Symbol Characteristic/Device				Тур†	Max	Units	Conditions			
	Vdd	Supply Voltage								
D001		PIC16LC54A	3.0 2.5	_	6.25 6.25	V V	XT and RC modes LP mode			
D001A		PIC16C54A	3.0 4.5	_	6.25 5.5	V V	RC, XT and LP modes HS mode			
D002	Vdr	RAM Data Retention Voltage <sup>(1)</sup>	—	1.5*	—	V	Device in SLEEP mode			
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	—	Vss	—	V	See Section 5.1 for details on Power-on Reset			
D004	SVDD	VDD Rise Rate to ensure Power-on Reset	0.05*	—	-	V/ms	See Section 5.1 for details on Power-on Reset			
	IDD	Supply Current <sup>(2)</sup>								
D005		PIC16LC5X	_	0.5	2.5	mA	Fosc = 4.0 MHz, VDD = 5.5V, RC <sup>(3)</sup> and XT modes			
				11	27	μΑ	Fosc = 32 kHz, VDD = 2.5V, WDT disabled, LP mode, Commercial			
			_	11	35	μΑ	Fosc = 32 kHz, VDD = 2.5V, WDT disabled, LP mode, Industrial			
D005A		PIC16C5X	—	1.8	2.4	mA	Fosc = 4.0 MHz, VDD = 5.5V, RC <sup>(3)</sup> and XT modes			
			—	2.4	8.0	mA	FOSC = 10 MHz, VDD = 5.5V, HS mode			
			—	4.5	16	mA	FOSC = 20  MHz,  VDD = 5.5V, HS mode			
				14	29	μA	HOSC = 32 kHz, VDD = 3.0V,			
			-	17	37	μΑ	Fosc = 32 kHz, VDD = 3.0V, WDT disabled, LP mode, Industrial			

Legend: Rows with standard voltage device data only are shaded for improved readability.

These parameters are characterized but not tested.

- † Data in "Typ" column is based on characterization results at 25°C. This data is for design guidance only and is not tested.
- **Note 1:** This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
  - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
    - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/ disabled as specified.
    - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
  - 3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in k $\Omega$ .

### 15.1 DC Characteristics: PIC16C54A-04, 10, 20 (Commercial) PIC16C54A-04I, 10I, 20I (Industrial) PIC16LC54A-04 (Commercial) PIC16LC54A-04I (Industrial)

PIC16LC54A-04 PIC16LC54A-04I (Commercial, Industrial)			$\begin{array}{ll} \mbox{Standard Operating Conditions (unless otherwise specified)} \\ \mbox{Operating Temperature} & 0^{\circ}C \leq TA \leq +70^{\circ}C \mbox{ for commercial} \\ -40^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for industrial} \end{array}$				
PIC16C54A-04, 10, 20 PIC16C54A-04I, 10I, 20I (Commercial, Industrial)			$\begin{array}{l} \mbox{Standard Operating Conditions (unless otherwise specified)} \\ \mbox{Operating Temperature} & 0^{\circ}C \leq TA \leq +70^{\circ}C \mbox{ for commercial} \\ -40^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for industrial} \end{array}$				
Param No.	Symbol	Characteristic/Device	Min	Тур†	Мах	Units	Conditions
	IPD	Power-down Current <sup>(2)</sup>					
D006		PIC16LC5X	—	2.5	12	μΑ	VDD = 2.5V, WDT enabled, Commercial
			—	0.25	4.0	μΑ	VDD = 2.5V, WDT disabled, Commercial
			_	0.25	5.0	μΑ μΑ	VDD = 2.5V, WDT enabled, industrial $VDD = 2.5V$ , WDT disabled, Industrial
D006A		PIC16C5X	_	4.0	12	μΑ	VDD = 3.0V, WDT enabled, Commercial
			—	0.25	4.0	μA	VDD = 3.0V, WDT disabled, Commercial
			—	5.0	14	μΑ	VDD = 3.0V, WDT enabled, Industrial
				0.3	5.0	μA	$v \Box U = 3.0v, v U T uisabled, industrial$

Legend: Rows with standard voltage device data only are shaded for improved readability.

\* These parameters are characterized but not tested.

† Data in "Typ" column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.

2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.

- a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/ disabled as specified.
- b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
- 3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in k $\Omega$ .

### 15.2 DC Characteristics: PIC16C54A-04E, 10E, 20E (Extended) PIC16LC54A-04E (Extended)

PIC16I C54A-04F			Stand	, ard One	ratino	, Condi	tions (unless otherwise specified)	
(Extended)			Operating Temperature $-40^{\circ}C \le TA \le +125^{\circ}C$ for extended					
PIC16C54A-04E, 10E, 20E (Extended)			Standard Operating Conditions (unless otherwise specified)Operating Temperature $-40^{\circ}C \le TA \le +125^{\circ}C$ for extended					
Param No.	Symbol	Characteristic	Min	Тур†	Мах	Units	Conditions	
	Vdd	Supply Voltage						
D001		PIC16LC54A	3.0 2.5		6.25 6.25	V V	XT and RC modes LP mode	
D001A		PIC16C54A	3.5 4.5		5.5 5.5	V V	RC and XT modes HS mode	
D002	Vdr	RAM Data Retention Voltage <sup>(1)</sup>		1.5*	—	V	Device in SLEEP mode	
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	-	Vss	_	V	See Section 5.1 for details on Power-on Reset	
D004	SVDD	VDD Rise Rate to ensure Power-on Reset	0.05*		_	V/ms	See Section 5.1 for details on Power-on Reset	
	IDD	Supply Current <sup>(2)</sup>						
D010		PIC16LC54A	-	0.5	25	mA	Fosc = 4.0 MHz, VDD = 5.5V, RC <sup>(3)</sup> and XT modes	
			-	11	27	μA	Fosc = 32 kHz, VDD = 2.5V, LP mode, Commercial	
			—	11	35	μA	Fosc = 32 kHz, VDD = 2.5V, LP mode, Industrial	
			—	11	37	μA	Fosc = 32 kHz, VDD = 2.5V, LP mode, Extended	
D010A		PIC16C54A	—	1.8	3.3	mA	Fosc = 4.0 MHz, VDD = 5.5V, RC <sup>(3)</sup> and XT modes	
			-	4.8	10	mA	Fosc = 10 MHz, VDD = 5.5V, HS mode	
			-	9.0	20	mA	Fosc = 20 MHz, VDD = 5.5V, HS mode	

Legend: Rows with standard voltage device data only are shaded for improved readability.

- \* These parameters are characterized but not tested.
- † Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.
- Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
  - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
    - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, TOCKI = VDD, MCLR = VDD; WDT enabled/ disabled as specified.
    - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
  - **3:** Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in kΩ.

Typical: statistical mean @ 25°C. Maximum: mean - 3 s (-40°C to 125°C) Minimum: mean

FIGURE 16-14: TYPICAL IDD vs. FREQUENCY (WDT DISABLED, RC MODE @ 300 PF, 25°C)

FIGURE 16-15: MAXIMUM IDD vs. FREQUENCY (WDT DISABLED, RC MODE @ 300 PF, -40°C to +85°C)





### FIGURE 18-17: PORTA, B AND C IOL vs. Vol, VDD = 3 V



## 19.0 ELECTRICAL CHARACTERISTICS - PIC16LC54C 40MHz

### Absolute Maximum Ratings<sup>(†)</sup>

Ambient temperature under bias	–55°C to +125°C
Storage temperature	–65°C to +150°C
Voltage on VDD with respect to VSS	0 to +7.5V
Voltage on MCLR with respect to Vss	0 to +14V
Voltage on all other pins with respect to Vss	–0.6V to (VDD + 0.6V)
Total power dissipation <sup>(1)</sup>	
Max. current out of Vss pin	
Max. current into Vod pin	
Max. current into an input pin (T0CKI only)	±500 μA
Input clamp current, IIK (VI < 0 or VI > VDD)	±20 mA
Output clamp current, Iок (Vo < 0 or Vo > Voo)	±20 mA
Max. output current sunk by any I/O pin	
Max. output current sourced by any I/O pin	
Max. output current sourced by a single I/O (Port A, B or C)	
Max. output current sunk by a single I/O (Port A, B or C)	
<b>Note 1:</b> Power dissipation is calculated as follows: Pdis = VDD x {IDD - $\sum$ IOH} + $\sum$ {(VI	-Voн) x Ioн} + ∑(Vol x Iol)

**†** NOTICE: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

## **19.3** Timing Parameter Symbology and Load Conditions

The timing parameter symbols have been created with one of the following formats:

1. TppS2ppS

2. TppS				
Т				
F	Frequency	T Time		
Lowercase letters (pp) and their meanings:				
рр				
2	to	mc MCLR		
ck	CLKOUT	osc oscillator		
су	cycle time	os OSC1		
drt	device reset timer	t0 T0CKI		
io	I/O port	wdt watchdog timer		
Uppercase letters and their meanings:				
S				
F	Fall	P Period		
Н	High	R Rise		
Ι	Invalid (Hi-impedance)	V Valid		
L	Low	Z Hi-impedance		

### FIGURE 19-2: LOAD CONDITIONS FOR DEVICE TIMING SPECIFICATIONS -PIC16C54C/C55A/C56A/C57C/C58B-40

